

IGBT Modules 1200V 150A DUAL

Manufacturers	Infineon Technologies Corporation
Package/Case	SMD
Product Type	Transistors
RoHS	
Lifecycle	



Images are for reference only

Please submit RFQ for BSM150GB120DN2 or [Email to us: sales@ovaga.com](mailto:sales@ovaga.com) We will contact you in 12 hours.

[RFQ](#)

General Description

BSM150GB120DN2 is a power semiconductor module manufactured by Infineon Technologies. It is a high-power switching device that is designed to handle large currents and voltages in industrial applications.

Features

It is a 1200V IGBT (Insulated Gate Bipolar Transistor) module with a maximum current rating of 150A.

It has a low on-state voltage drop, which helps to reduce power losses.

The module has a built-in temperature monitoring system that protects against overheating.

It is designed to be rugged and reliable, with a high level of resistance to thermal and electrical stress.

The module is equipped with fast-switching IGBTs, which makes it suitable for high-frequency applications.

Application

Industrial motor drives

Solar inverters

Uninterruptible power supplies (UPS)

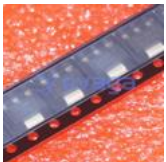
Welding equipment

Switched-mode power supplies (SMPS)





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